Simulation of Impurity Diffusion in a Strained Nanowire Using Off-lattice KMC

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Abstract. Kinetic Monte Carlo (KMC) is a stochastic model used to simulate crystal growth. However, most KMC models rely on a pre-defined lattice that neglects dislocations, lattice mismatch and strain effects. In this paper, we investigate the use of a 3D off-lattice KMC algorithm. We test this method by investigating impurity diffusion in a strained FCC nanowire. While faster than a molecular dynamics simulation, the most general implementation of off-lattice KMC is much slower than a lattice-based algorithm. An improved procedure is achieved for weakly strained systems by pre-computing approximate saddle point locations based on unstrained lattice structures. In this way, one gives up some of the flexibility of the general method to restore some of the computational speed of lattice-based KMC. In addition to providing an alternative approach to nano-materials simulation, this type of simulation will be useful for testing and calibrating methods that seek to parameterize the variation in the transition rates for lattice-based KMC using continuum modeling.

Key words: Off-lattice KMC, nanowire, strain rate, impurity diffusion

1 INTRODUCTION

Kinetic Monte Carlo (KMC) is a stochastic model that simulates the atomic details of crystal growth and evolution using probabilistic rules to govern deposition, diffusion and other transition processes. [1] This technique was first adopted in the early 1970’s [2,3] and has found many uses in surface diffusion on adsorbed mono layers, [4] growth of polymer crystals [5] and self-organized nanowires. [6] In contrast to the thermodynamic Monte

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Carlo methods, which are aimed at predicting the equilibrium state of molecular systems, KMC seeks to provide information about a systems evolution. In KMC, transition rates between states depend on both the energy of the configuration before hopping, as it would in other Monte Carlo techniques, and on the energy barrier between the states. [7] The aim of this method is to identify a significant set of possible events to describe the general behavior of evolution processes and to find the energy barrier between the saddle point and local minima for each of these. The principal KMC algorithm is based on the method of Bortz, Kalos and Lebowitz [8] (BKL), which will be introduced in section II.

In KMC, all lattice points, energy barriers and diffusion rates are normally defined before computation begins. As a consequence, dislocations, lattice mismatch and strain effects are neglected. A molecular dynamics (MD) simulation can be used for off-lattice simulation, however, it is limited to a time scale on the order of $10^{-6}$ seconds or less. An off-lattice KMC (OLKMC) simulation can be used for longer simulations while taking into account some elastic effects. Off-lattice KMC will also be useful for testing and calibrating other macroscopic tools, such as schemes that aim to combine continuum modeling with KMC.

Off-lattice simulations themselves can be implemented in a number of ways, with the usual tradeoff between faithful representation of the physical processes and computational speed. At one extreme, Jonsson et. al. [9] have implemented a method that uses harmonic transition state theory (TST), described below, to estimate transition rates between local minima for the energy landscape in the full $n$-particle configuration space. Further, they make no assumptions about the approximate location of the saddle points separating two energy minima. This represents the most computationally intensive version of OLKMC, where random initial guesses must be used to locate transition points. In this method, locating the set of transition points is the most costly part of the algorithm. Even with parallel implementation this type of calculation is presently limited to a few hundred atoms or less.

An approach which is less computationally intensive, but less accurate, is found in the work of Much et al. [10, 11] in which an OLKMC algorithm has been developed to simulate the early stage of heteroepitaxial growth for adsorbate layers. A simple Lennard-Jones potential is employed in their simulation. The transition points are sought in a “frozen crystal” approximation where only a single atom is moved within the configuration space in order to locate approximate saddle points. This method is used to simulate surface diffusion during “1+1”-dimensional epitaxial growth and submonolayer “2+1”-dimensional growth growth. The resulting simulation is considerably faster, but still does not approach the computational speed of lattice based simulation and the saddle point problem is again the most intensive part of the algorithm.

Still another approach to incorporating elastic effects into KMC found in the work of [12]. These authors use a model where the transition rate is approximated using only the binding site energy, the atoms interact through a nearest neighbor network of linear springs and the energy is calculated using a displacement field relative to a fixed lattice.

In this paper, we investigate an OLKMC method that relies on having approximate
saddle point locations, allowing the method to function in three dimensions for a few thousand particles. We consider saddle-point computation using both a relaxation of the full configuration as well as the frozen-crystal approximation in order to assess the reliability of the latter. An important improvement over the previous work is the implementation of an a priori (over-)estimate for the transition rate and subsequent rejection of some moves upon calculation of the actual rate. Another method combining rejection and rejection-free KMC can be found in the recent work of Devita, Smereka and Sander [13–15].

Our method is motivated by the need to simulate off-lattice phenomena in various nanoscale devices. As a benchmark problem, we examine interstitial diffusion in crystalline nanomaterials. While this is a topic of interest in technological applications, [16,17] our interest here is principally in evaluating a particular approach to molecular simulation. Specifically, our prototype problem considers impurity diffusion in a strained FCC nanowire. The rest of this paper is divided into four parts: an explanation of the OLKMC method, the application of the method to our prototype problem, our results and some concluding remarks.

2 Description of Method

The total potential energy is modeled using classical, empirical formulas like the Lennard-Jones potential, [18] which is a sum of pair-wise interactions, or the embedded atom potential. [19,20] As it is sufficient to illustrate the method, we primarily focus on the Lennard-Jones potential:

$$\Phi = \sum_{ij} \Phi_{ij} = 4U_a \sum_{ij} \left[ \left( \frac{\sigma}{d_{ij}} \right)^{12} - \left( \frac{\sigma}{d_{ij}} \right)^{6} \right], \tag{2.1}$$

where $U_a$ represents the depth of the energy well that an atom in equilibrium resides in, $\sigma$ represents a length scale for the mean particle separation in equilibrium and $d_{ij}$ is the distance between particle $i$ and $j$. In our simulations, we will use non-dimensional units for length, where we scale the lengths with $\sigma$. For the primary crystal, we use the non-dimensional length $\sigma^*_a = 1$ and $U_a = 0.15$ ev for the depth of the energy well. For simplicity, we will omit the asterisk below. Such potential functions contain an enormous number of local minima in the 3N-dimensional configuration space consisting of the particle position vectors $\mathbf{x}_i \in \mathbb{R}^3$. These local minima serve as the temporary resting places of particles in the zero-temperature approximation and, more generally, as approximate locations of the basins of attraction for particle positions in low-temperature, solid-phase materials. In a corresponding molecular dynamics simulation, all of the particles will undergo Brownian-like motions that are largely localized within these basins, but also feature infrequent transitions where the system moves from one basin (local minimum) to a neighboring minimum in the configuration space. According to transition state theory, [21] the rate at which these transitions are made is related to the energy barrier that must be overcome in crossing the saddle-points that separate neighboring local minima.
In a general solid-phase material with grain boundaries, dislocations and irregular surface structure, there will be an undetermined number of these near-by saddle points associated with a given local minimum. We limit our model to transitions involving a single impurity atom diffusing in the interstices of a strained lattice. While not all likely transition pathways will be detected by this procedure—concerted moves of impurity clusters, for example—intuition suggests that most will and that it is one of the simplest ways to efficiently address large configurations. To further enhance computational performance, we employ a cut-off length \( \sigma_c \), so that if \( d_{ij} > \sigma_c \) we ignore the contribution of the term \( \Phi_{ij} \) to the total potential (2.1). In addition to greatly reducing the number of pair potential calculations, the matrix of interactions becomes sparse when the cutoff is employed. In this paper, the cutoff is normally chosen to be three times the mean particle separation.

With these two approximations in place, the OLKMC method reduces to a combination of optimization and the standard algorithms for KMC. From an optimization perspective, there are two types of problems involved. First, the material must be relaxed within the configuration space to its local minimum. For each attempted event a second calculation must then be made to determine the saddle-point energy. In this paper, all optimization is performed using a nonlinear conjugate gradient algorithm along with accurate initial guesses derived from a perfect lattice that improve convergence and avoid numerical instabilities. For the local minima we minimize the energy directly; for the saddle-points we minimize \( |\nabla \Phi|^2 \). Both absolute and relative convergence criteria are employed. We use the maximum norm of the potential (or \( |\nabla \Phi|^2 \) for saddle points) for the absolute convergence criteria and the maximum norm of the displacement vector for relative convergence:

\[
\max_i |\nabla_3 \Phi(x_i)| < \epsilon_3, \tag{2.2a}
\]

\[
\max_i |\mathbf{x}^{n+1}_i - \mathbf{x}^n_i| < \epsilon_4. \tag{2.2b}
\]

Computationally, this is still an enormously expensive task with limited feasibility unless further approximations are made. To this end, we also explore focusing the relaxation algorithm on a subset of the particles surrounding the particle making a transition.

Initially the rates for all events are estimated using rates \( r_n \) for the \( n \)th event that are greater than any actual rates. To select one event among the many possibilities, a standard BKL algorithm \[8\] is used, in which the overall transition rate \( S_N = \sum^n_{n=1} r_n \) is computed, retaining the partial sums \( S_n \). A random number \( r \in [0, S_N] \) is then selected and one searches through a list of events until \( r < S_n \). For lattice-based KMC, it is important to make this search efficient, but the search represents a very small part of the computation for OLKMC. Following standard KMC practice, the time interval between two events can be selected randomly from a Poisson distribution \( \Delta t = -\frac{\log(u)}{S_N} \), where \( u \) is a uniformly distributed random number \([0, 1]\). The actual energy barrier for the selected transition is then calculated using harmonic transition state theory \[21\] by

\[
r(\Delta \Phi, T) = k_0 \exp \left( \frac{-\Delta \Phi}{k_B T} \right), \tag{2.3}
\]
where $\Delta \Phi$ represents the energy barrier between the transition state and binding state. Here, $T$ denotes the temperature, $k_B$ is the Boltzmann constant and $k_0$ is the attempt frequency. An event is accepted or rejected using a comparison of where the random number $r$ and the true rate fall within the interval between two successive partial sums $S_n$. An accepted event is realized by moving this atom to the approximate location of its new position where it will be re-relaxed at the beginning of the next iteration.

3 Impurity Diffusion in a Strained FCC nanowire

As a prototype problem, we test the algorithm in the context of impurity diffusion in a strained FCC nanowire. Figure 1(a) shows an FCC unit cell which can be decomposed into one octahedral section and eight tetrahedral sections, as shown in Fig. 1(b). If the repulsive interaction between the impurity and the lattice particles is tuned appropriately, the impurity particles will occupy local minima at the centers of these polyhedral regions, as shown in Fig. 1(b). We use the perfect FCC lattice to generate initial guesses for the local minima and saddle points of a strained lattice. This allows us to efficiently simulate the interstitial diffusion of impurities in weakly strained crystals.

The ideal FCC lattice can be defined using integer combinations of three basis vectors

$$a = \frac{i + j}{\sqrt{2}} \times a_c \quad b = \frac{i + k}{\sqrt{2}} \times a_c \quad c = \frac{k + j}{\sqrt{2}} \times a_c,$$

where $a_c = \sqrt{2} \sigma$ is the equilibrium distance between two atoms in an isolated environment. An arbitrary lattice point can be defined by $v = n_1 a + n_2 b + n_3 c$. As shown in Fig. 2, we define the nanowire geometry by orientating the axis parallel to a unit vector $\mathbf{n}$, chosen orthogonal to a faceting direction, and include in the initial wire all lattice points $\mathbf{v}$ satisfying

$$|\mathbf{v} \cdot \mathbf{n}| \leq L,$$  \hspace{1cm} (3.2a)

$$|\mathbf{v} - (\mathbf{v} \cdot \mathbf{n})\mathbf{n}| \leq R,$$  \hspace{1cm} (3.2b)

where $L$ and $R$ are the length and radius of the nanowire respectively. Each local energy minimum has a number of saddle points associated with it. Figure 3(a) and Figure 3(b) show octahedral (O) and tetrahedral (T) sites, respectively, with an impurity at their centers. The small spheres at the center of each face represent near-by saddle points while the large spheres represent the local minima. For an octahedron, there are eight saddle points while there are four for a tetrahedron. In the search for the location of saddle points in a strained system, initial guesses can be based on these ideal structures. For example, when an impurity rests in an O-site, the initial guesses are

$$\mathbf{x} = \mathbf{x}_{eq} + d_O \times \mathbf{e}_i^T, \quad i \in \{1, 2, \ldots, 8\},$$

where $\mathbf{x}_{eq} \in \mathbb{R}^3$ is a local minimum. The distance between the local minimum and saddle point is $d_O$ and $\{\mathbf{e}_i\}$ is a set of eight unit vectors pointing in the direction of the initial
Figure 1: FCC unit cell composed of one octahedral section and eight tetrahedral sections. (a) FCC unit cell and (b) Decomposition of FCC unit cell.

Figure 2: FCC nanowire with its axis parallel to a unit vector \( \hat{u} \), chosen orthogonal to a faceting direction. Here, \( L \) and \( R \) are the length and radius of the nanowire, respectively.
Figure 3: Illustration of local minima and corresponding saddle points. The small spheres at the center of each face represent near-by saddle points while the larger spheres represent the local minima. (a) Octahedron and (b) Tetrahedron.

Guesses

\[
\begin{pmatrix}
  e_1 \\ e_2 \\ e_3 \\ e_4 \\ e_5 \\ e_6 \\ e_7 \\ e_8 
\end{pmatrix}
=
\frac{1}{\sqrt{3}}
\begin{pmatrix}
  1 & 1 & 1 \\
  -1 & -1 & 1 \\
  1 & 1 & -1 \\
  -1 & -1 & -1 \\
  1 & -1 & 1 \\
  -1 & 1 & 1 \\
  1 & -1 & -1 \\
  -1 & 1 & -1 
\end{pmatrix}
\]  

The distance \( d_O \) can be expressed in terms of \( a_e \) based on the geometry of an octahedron

\[
d_O = \frac{\sqrt{6}a_e}{6}. \tag{3.5}
\]

For a T-site, the initial guesses are

\[
x = x_{eq} + d_T \times e_j^T,
\quad i \in \{1, 2, \ldots, 8\},
\quad j \in \{1, 2, 3, 4\},
\]

where \( d_T \) is the distance between the local minima and saddle point

\[
d_T = \frac{(5\sqrt{6} - 3\sqrt{10})a_e}{15}. \tag{3.7}
\]

As shown in Fig. 1(b), an O-site is adjacent to eight T-sites, each having a distinct orientation. The set of initial guesses can be formed from the same guesses \( \{e_i\} \) used in the
octahedral case, but must be indexed by both the eight possible tetrahedral orientations and the four faces of each tetrahedron. Thus, \( \mathbf{e}_{ij} \in \mathbb{R}^3 \) represents an initial guess for the \( i \)th orientation and the \( j \) face:

\[
\begin{pmatrix}
\mathbf{e}_{11} & \mathbf{e}_{12} & \mathbf{e}_{13} & \mathbf{e}_{14} \\
\mathbf{e}_{21} & \mathbf{e}_{22} & \mathbf{e}_{23} & \mathbf{e}_{24} \\
\mathbf{e}_{31} & \mathbf{e}_{32} & \mathbf{e}_{33} & \mathbf{e}_{34} \\
\mathbf{e}_{41} & \mathbf{e}_{42} & \mathbf{e}_{43} & \mathbf{e}_{44} \\
\mathbf{e}_{51} & \mathbf{e}_{52} & \mathbf{e}_{53} & \mathbf{e}_{54} \\
\mathbf{e}_{61} & \mathbf{e}_{62} & \mathbf{e}_{63} & \mathbf{e}_{64} \\
\mathbf{e}_{71} & \mathbf{e}_{72} & \mathbf{e}_{73} & \mathbf{e}_{74} \\
\mathbf{e}_{81} & \mathbf{e}_{82} & \mathbf{e}_{83} & \mathbf{e}_{84}
\end{pmatrix} =
\begin{pmatrix}
\mathbf{e}_3 & \mathbf{e}_4 & \mathbf{e}_5 & \mathbf{e}_6 \\
\mathbf{e}_3 & \mathbf{e}_4 & \mathbf{e}_5 & \mathbf{e}_6 \\
\mathbf{e}_1 & \mathbf{e}_2 & \mathbf{e}_7 & \mathbf{e}_8 \\
\mathbf{e}_1 & \mathbf{e}_2 & \mathbf{e}_7 & \mathbf{e}_8 \\
\mathbf{e}_1 & \mathbf{e}_2 & \mathbf{e}_7 & \mathbf{e}_8 \\
\mathbf{e}_3 & \mathbf{e}_4 & \mathbf{e}_5 & \mathbf{e}_6 \\
\mathbf{e}_3 & \mathbf{e}_4 & \mathbf{e}_5 & \mathbf{e}_6
\end{pmatrix}.
\]

(3.8)

Here the faces of the tetrahedron have been labeled so that each row in the matrix on the right-hand side is repeated four times.

For these initial guesses to be valid, the impurity must interact relatively weakly with the primary crystal, so that the FCC structure remains intact. Also, the equilibrium separation between an impurity and a lattice particle must be larger than the distance separating the central point in the O- or T-sites from the centers of their respective faces. If the latter condition is not met, there will be a different local minima structure for impurity locations where local minima are associated with each undeformed lattice site in a sattleight configuration. With these considerations in mind, we model the interaction of the impurity with the primary material forming the lattice using a Lennard Jones potential (2.1) with different material parameters. For interactions between impurities, we use the values \( U_b = 0.1 \) eV and \( \sigma_b = 0.4 \sigma_a \). The interaction between a nanowire particle and an impurity is defined by \( U_{ab} = \sqrt{U_a U_b} \) and \( \sigma_{ab} = (\sigma_a + \sigma_b)/2 \).

To simulate impurity diffusion in strained nanowires, we first uniformly stretch or compress the wire by transforming the axial coordinate \( z \rightarrow (1 + \epsilon)z \) and then relax the transformed configuration to the local minimum that this approximates while constraining the layers of atoms at the ends of the nanowire. We assume all impurities evaporate once they reach the nanowire wall.

4 RESULTS

We begin by illustrating diffusion of a single impurity in a statically strained nanowire. Figures 4(a) and 4(b) show a sample path that demonstrates the detailed trajectory of one impurity diffusing from the central point to the boundary of a nanowire. The impurity alternately diffuses through the adjacent O- and T-sites. The binding energy in T-sites is higher than that in O-sites, so that the impurity binds preferentially in the O-sites and, on average, the time intervals spent in these sites is much longer than in the T-sites. This is consistent with one's intuition and in agreement with existing theory. [16]

Figure 5 illustrates a simulation with multiple impurities diffusing simultaneously. Several O-sites are randomly selected as initial impurity locations. In the case when
adjacent O and T-sites are occupied, the number of saddle points is less than eight in an O-site and less than four in a T-site. Figures 5(a)-5(b) show both the side and top view of the final position distribution for a simulation with multiple impurities.

To test our code and as a step toward building a faster lattice-based KMC that accounts for elastic effects using tabulated rates and interpolation, we have collected a number of energy barriers in table I using a 3N relaxation scheme. The table shows the energy barriers for a single adatom in a central O or T site diffusing in each of the eight possible directions defined in Eq. (3.4 ) with 1% and 2% strain along the three principal faceting directions 100, 110 and 111. The unstrained numbers are 0.833 ev for an O-site and 0.125 ev for a T-site. Note that the rates for a given axis orientation come in groups that are consistent with the symmetry of the given axis.

For reasons of comparison, we also have collected the same number of energy barriers for a single adatom using a frozen approximation method, where the potential energy landscape is probed for saddle points by moving only a single atom at a time. Now, it is clear from the comparison that neglecting the distortion of the crystal around the hopping atom will give much higher energy barrier in the case of interstitial diffusion.

Next we explore the possibility of using some type of frozen crystal approximation, by constraining all but a limited set of atoms in the vicinity of the hopping atom. These results are shown in Figures 6(a)-6(b) where we plot the energy barrier value obtained as a function of the number of unconstrained neighbors in the calculation. Figures 6(a)-6(b) show that one can obtain about 95% ’s accuracy of energy barrier for an O-site by relaxing 50 unconstrained neighbors while a 92%’s accuracy can be obtained using 100 unconstrained neighbors for a T-site. As a result, we have used this frozen crystal method, where a cut-off distance \( r = 3a \) is selected for unconstrained neighbors of an adatom at an O-site center of a nanowire, to simulate the energy barriers under various
Figure 5: Diffusion of multiple impurities. (a) Final positions of multiple impurities and (b) Top view of multiple impurities.

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Table 1: This table shows the energy barriers for a single adatom in a central O and T site diffusing in each of the eight possible directions defined in Eq. (3.4) with 1% and 2% strain along the three principal faceting directions 100, 110 and 111. The total number of atoms in the nanowire for the 100, 110 and 111 cases is 946, 990 and 1012, respectively. The data for Table 1 was calculated by relaxing the full system.
strains perpendicular to different crystal orientations. Figures 7(a)-7(c) show us that the jump rate for a single atom is not uniformly altered by a macroscopic strain. For instance, stretching a nanowire along the faceting direction of 100 will uniformly decrease the energy barrier for each of the eight possible directions defined in Eq. (3.4) with 1% and 2% strain along the three principal faceting directions 100, 110, and 111. The total number of atoms in the nanowire for the 100, 110, and 111 cases is 946, 990, and 1012, respectively.

As shown in Figure 8, the energy barriers are relatively uniform in the interior of the uniformly stretched wire. Hence, one can correct the energy barrier by adding a constant to it in order to employ the frozen crystal method. There are, however, significant variations as one approaches the surface of the wire. This type of surface effect is especially important in heteroepitaxy. Our results suggest the possibility of a hybrid simulation that combines lattice-based KMC in the interior and off-lattice KMC near the surface. Unlike the present implementation, however, it is extremely difficult to anticipate the approximate location of transition points near surfaces due to reconstruction, especially for strained surfaces.

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Table 2: This table shows the energy barriers, calculated using the frozen crystal approximation, for a single adatom in a central O and T site diffusing in each of the eight possible directions defined in Eq. (3.4) with 1% and 2% strain along the three principal faceting directions 100, 110, and 111. The total number of atoms in the nanowire for the 100, 110, and 111 cases is 946, 990, and 1012, respectively.

5 CONCLUSION

We have implemented a 3D OLKMC algorithm capable of simulating off-lattice phenomena in various nanodevices. This method differs from previous off-lattice work in that it is aimed at weakly strained systems where the lattice geometry can provide good initial
Figure 6: A plot of the energy barrier obtained as a function of the number of unconstrained neighbors for an O-site and T-site at the center of a wire under 2% strain and oriented perpendicular to the \{100\} facet.
Figure 7: A plot of the energy barrier versus strain for an O-site at the center of different orientation wires using a frozen method, where a cut off distance $r = 3 \times a$ is selected for unstrained neighbors. (a) Direction of 100, (b) Direction of 110 and (c) Direction of 111.
guesses for transition points. In order to demonstrate the method, we examined a strained FCC nanowire using a Lennard-Jones potential. We explored the possibility of some type of frozen crystal approximation and found that although neglecting the distortion of neighbor crystal gives rise to a much higher energy barrier, one can still employ the frozen crystal approximation by adding a constant to the energy barrier. Our simulation shows us that the jump rate for an adatom is not uniformly altered by a macroscopic strain, depending on the stretching direction as well as the hopping direction of an adatom. We provided evidence that suggests rates in regions of the crystals with a slowly varying elastic field could be computed on a coarsened length-scale and tabulated for use in a lattice-based approach in these regions.

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